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EXAMINATION AND EVALUATION DIVISION DEPARTMENT OF POLYTECHNIC EDUCATION (MINISTRY OF HIGHER EDUCATION)

ELECTRICAL ENGINEERING DEPARTMENT

FINAL EXAMINATION JUNE 2012 SESSION

EE201: SEMICONDUCTOR DEVICES

DATE: 20 NOVEMBER 2012 (TUESDAY)
DURATION: 2 HOURS (8:30 AM TO 10.30 AM)

This paper consists of TEN (10) pages including the front page.

Section A1 : Objective (10 Question)

Section A2: Fill in the blank (10 Question)

Section B : Structured (10 Question)

Section C: Essay (2 Question)

Answer all questions

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(The CLO stated is for reference only.)



OBJECTIVE

Instructions: This section consists of 20 objective questions. Answer all questions in the answers booklet.

- 1. Which of the following statements explain the term a semiconductor? [CLO1]
 - A. Valence electron are weakly attracted to the nucleus of the atoms
 - B. Material that behaves in between a conductor and insulator.
 - C. The substance that resist the flow of electric current.
 - D. High amount of free mobility electrons.
- 2. Which of the following statements is NOT the diode application in an electronic circuit?. [CLO1]
 - A. Diode as Clipper.
 - B. Diode as Rectifier.
 - C. Diode as Amplifier.
 - D. Diode as Clamper
- 3. A full-wave bridge rectifier consists of

[CLO2]

- A. 1 Diode
- B. 2 Diodes
- C. 3 Diodes
- D. 4 Diodes

	CONFIDENTIAL EE201 – Semion 7. Given $I_B = 125 \mu A$ and $\beta = 200$, the collector current will be	conductor Devices [CLO 2]
	Α. 25μΑ	
1	B. 25mA	
	C. $0.0025\mu A$	
]	D. 0.025mA	
	8. N-Channel FETs are superior to P-Channel FETs because	[CL01]
1	A. They have higher input impedance	
10	B. They have high switching time	
	C. They consume less power	
J	D. Mobility of electrons is greater than that of holes	
	9. The supply voltage that is connected directly or indirectly to the drain of a FET is presented by	[CLO1]
	A. V_{GS}	[CLOI]
1	B. V _{DS}	
	$C. V_{SS}$	
]	D. V _{DD}	
lo	10. Below are the THREE (3) applications for Unijunction Transistor	
]	(UJT) EXCEPT	[CLO1]
	A. timer circuit	
	B. phase control	
]	C. voltage regulator	
J	D. signal generator circuit	

11. The minority carriers in P-type silicon are called	[CLO2]
12. Testing a good diode with an ohmmeter should indicate	
resistance when reverse biased and	
resistance when forward biased.	[CLO1]
13. When the polarity of the battery is such that electrons are allowed t	0
flow through the diode, the diode is said to be	[CLO1]
14. Cascaded Amplifier is a connection of two or more ampli	fiers.
The basic purpose of a Cascaded Amplifier is to	
the voltage gain.	[CLO1]
15. The most commonly used counting in an arralification	
15. The most commonly used coupling in an amplifier is	_ [CLO1]
16. Common Collector configuration shows that	
terminal will be connected to ground.	[CLO 1]
17 Recide used as an amplifier RIT also used as a	
17. Beside used as an amplifier, BJT also used as a	[CLO 1]
18. An E-MOSFET works only with gate voltages.	[CLO 2]

19. Refer to Figure 1 below. The I-V curve belongs to _____ [CLO 1]

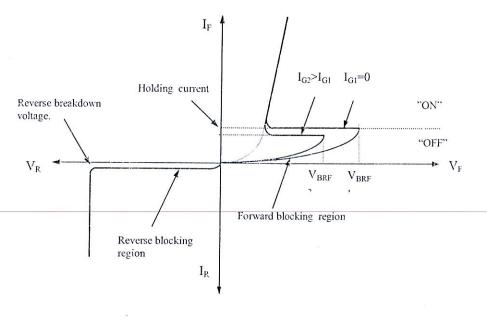


Figure 1

20. In an SCR, the function of the gate is to _____. [CLO2]

SECTION B

STRUCTURED (30 marks)

Instruction: This section consists of 10 structured questions. Answer ALL questions

QUESTION 1

Give THREE (3) factors which enable electron to be free from the covalent bond.

[CLO2]

(3 marks)

QUESTION 2

Draw the symbol of LED and give the example of its application. [CL

[CLO2]

(3 marks)

QUESTION 3

If p-type material is connected to the negative terminal of the power supply, what will happen to:-

i. Depletion region

(1 mark)

ii. Resistance

(1 mark)

iii. Current flow

(1 mark)

QUESTION 4

Draw and label the block diagram of Multistage Amplifier.

[CLO 1]

(3 marks)

QUESTION 5

State the differences between negative and positive feedback in an amplifier. [CLO 1]

(3 marks)

Figure 2

SECTION C

ESSAY (50 marks)

INSTRUCTION:

This section consists of TWO (2) essays questions.

Answer all the questions.

QUESTION 1

Based on the Figure 3, answer the following questions.

Value given for $V_{GH} = 20Vp-p$, 50Hz

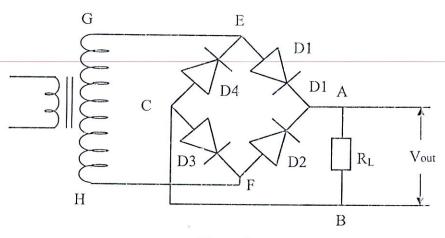


Figure 3

a. Draw the wave form at point G-H.

(4 marks)

[CLO2]

b. Draw the wave form at point A-B. [CLO 2]

(4 marks)

c. Determine the value of V_{out}. [CLO 2]

(5 marks)

d. Explain how the diodes in circuit diagram operate. [CLO 2]

(12 marks)

QUESTION 2

a. State the TWO (2) configurations of BJT and draw the connections.

[CLO 2]

(3 marks)

b.

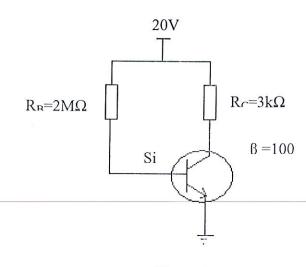


Figure 4

With reference to Figure 4, calculate the value of

[CLO 2]

i) I_B

(3 Marks)

ii) I_{CQ}

(3 Marks)

iii) V_{RC}

(3Marks)

iv) V_{CQ}

(3 Marks)

v) Saturation Point

(3 Marks)

vi) Cut-off point

(3 Marks)

c. Draw the DC Load Line for Figure 4.

[CLO 2]

(4 Marks)